



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of: Doo Yeol RYOO

Serial No.: 10/615,238

Group Art Unit: 2814

Filed: July 9, 2003

Examiner: Pham, Long

For: TRANSISTOR IN SEMICONDUCTOR DEVICES AND METHOD OF
FABRICATING THE SAME

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RESPONSE TO RESTRICTION REQUIREMENTHonorable Commissioner for Patent
P.O. Box 1450
Alexandria, VA 22313-1450

January 15, 2004

Sir:

In response to the Request for Restriction mailed January 5, 2004 (Paper No. 12302003), Applicant elects Group I, claims 5-12, drawn to a method for making a semiconductor device, classified in class 438, subclass 275, with traverse.

Applicant respectfully traverses the restriction requirement. The claims of Group I (Claims 5-12) drawn to a method for making a semiconductor device and the claims of Group II (Claims 1-4) drawn to a semiconductor device are closely related to each other and define a single invention. The semiconductor device defined in claims 1-4 is manufactured by the method of claims 5-12, and thus, claims 1-12 define a single inventive concept. Further, Applicant respectfully submits that it would not be unduly burdensome for the Examiner to examine the claims of both groups. Applicant respectfully requests that claims 1-12 be examined.

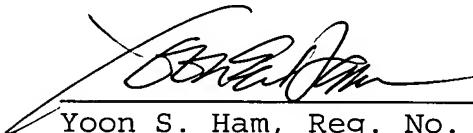
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Atty. Docket No.: P68972US0

An early Office Action on the merits is respectfully requested.

If a Petition for Extension is necessary and the petition and/or payment of the fee(s) is not enclosed, this will act as a petition to extend the time for response and authorization to charge the necessary fee(s) under 37 CFR 1.17(a)-(d) to Deposit Account 06-1358.

Respectfully submitted,



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